



#### 3A, 4.5A, 5.5A PWM STEP-UP DC-DC CONVERTER

### **Description**

The PAM242x devices are high-performance, fixed frequency, current-mode PWM step-up DC/DC converters that incorporate internal power MOSFETs. The PAM242x includes an integrated power MOSFET that supports peak currents of up to 3A/4.5A/5.5A.

The PAM242x utilize simple external loop compensation allowing optimization between component size, cost, and AC performance across a wide range of applications. Additional functions include an externally programmable soft-start function for easy inrush current control, internal overvoltage protection (OVP), cycle-by-cycle current limit protection, undervoltage lock-out, and thermal shutdown.

The PAM242x are available in the small SO-8EP package.

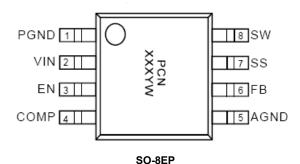
#### **Features**

- · Greater than 90% Efficiency
- Adjustable Output Voltage Up to 24V
- Internal 24V Power MOSFET
- Peak Current 3A, 4.5A, 5.5A
- 520kHz Frequency
- Built-In Overvoltage Protection (OVP)
- Open Protection
- Programmable Soft-Start Function
- Thermal Shutdowns
- Undervoltage Lockout
- Overcurrent Protection
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative.

https://www.diodes.com/quality/product-definitions/

### **Pin Assignments**

### (Top View)



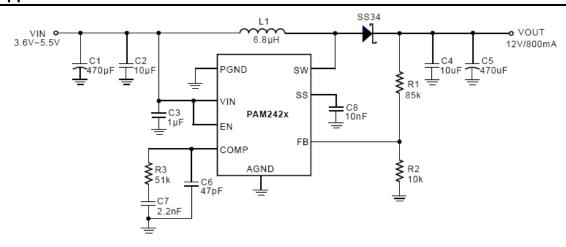
### **Applications**

- TFT LCD Monitors
- Battery-Powered Equipment
- Set-Top Boxes
- DSL and Cable Modems and Routers

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

## **Typical Applications Circuit**

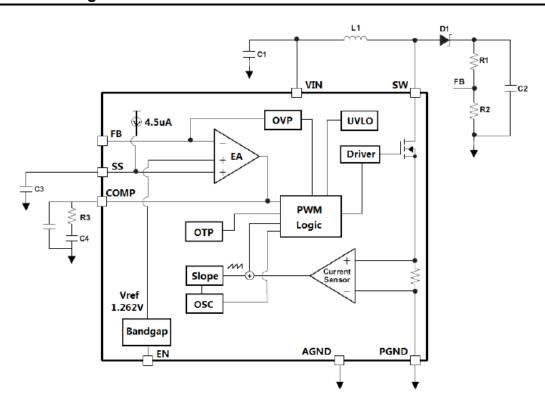




## **Pin Descriptions**

Pin Number	SO-8EP Pin Name	Function
1	PGND	Power Ground
2	VIN	Supply Input
3	EN	Enable Control. Connect to a logic high level to enable the IC. Connect to a logic low level to disable the IC. When unused, connect EN pin to VIN (do not leave pin floating).
4	COMP	Error Amplifier Compensation Node
5	AGND	Analog Ground
6	FB	Feedback Input. Connect this pin a resistor divider from the output to set the output voltage. FB is regulated to 1.262V.
7	SS	Soft Start Control Input. Connect a capacitor from this pin to Ground to set soft-start timing duration. SS is discharged to ground in shutdown. SS may be left unconnected if soft start is not desired.
8	SW	Switch Output. Connect this pin to the inductor and the Schottky diode. To minimize EMI, minimize the PCB trace path between this pin and the input bypass capacitor.
_	Exposed Pad	Connected to Ground

## **Functional Block Diagram**





## Absolute Maximum Ratings (@ T<sub>A</sub> = +25°C, unless otherwise specified.)

These are stress ratings only and functional operation is not implied. Exposure to absolute maximum ratings for prolonged time periods may affect device reliability. All voltages are with respect to ground.

Parameter	Rating	Unit
SW to Ground	-0.3 to +28	V
VIN, EN, FB, SS, COMP to Ground	-0.3 to +6.5	V
Continuous SW Current	Internally Limited	A
Operating Temperature Range	-40 to +150	°C
Storage Temperature Range	-55 to +150	°C
Lead Temperature (Soldering, 10s)	300	°C

## Recommended Operating Conditions (@ T<sub>A</sub> = +25°C, unless otherwise specified.)

Parameter	Rating	Unit
Junction Temperature Range	-40 to +125	ç
Ambient Temperature Range	-40 to +85	O

### **Thermal Information**

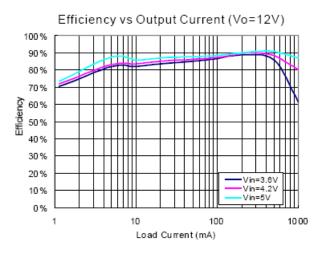
Parameter	Symbol	Package	Max	Unit
Thermal Resistance (Junction to Case)	θЈС	SO-8EP	75	°C/W
Thermal Resistance (Junction to Ambient)	θ <sub>JA</sub>	SO-8EP	180	C/VV

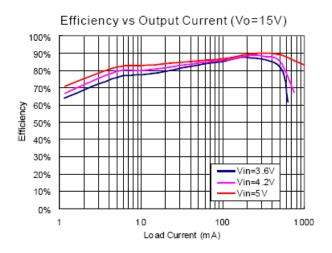
## **Electrical Characteristics** (@ $T_A$ = +25°C, $V_{IN}$ = $V_{EN}$ = 5V, unless otherwise specified.)

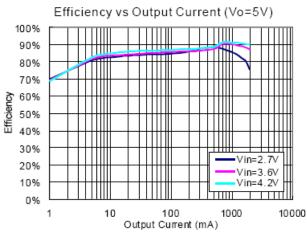
Parameter	Test Conditions		Min	Тур	Max	Unit	
Input Voltage	_		2.7	_	5.5	V	
Undervoltage Lockout Threshold	V <sub>IN</sub> Rising		_	2.5	_	V	
Undervoltage Lockout Hysteresis	_		_	200	_	mV	
Out a sent Outside	V <sub>FB</sub> = 1.4V, Not Switching		_	0.25	0.35	- mA	
Quiescent Supply	V <sub>FB</sub> = 1.0V, Swite	V <sub>FB</sub> = 1.0V, Switching		3	5		
Supply Current in Shutdown	EN = Ground		_	0.1	1.0	μA	
Switching Frequency	_		_	520	_	kHz	
Maximum Duty Cycle	_		85	_	_	%	
FB Feedback Voltage	_		1.230	1.262	1.294	V	
FB Input Current	_	_		0	80	nA	
FB Voltage Line Regulation	V <sub>FB</sub> from 2.7V to	V <sub>FB</sub> from 2.7V to 5.5V		0.05	0.15	%/V	
	PAM2421	.,	3	_	_	А	
Switch Current Limit	PAM2422	V <sub>IN</sub> = 3.2V Duty Cycle = 70%	4.5	_	_		
	PAM2423	Duty Cycle - 70%	5.5	_	_		
	PAM2421	_	_	130	_		
Switching On Resistance	PAM2422	_	_	100	_	mΩ	
	PAM2423	_	_	70	_	]	
Switch Leakage Current	V <sub>SW</sub> = 10V, EN = Ground		_	_	15	μA	
Soft-Start Pin Bias Current	V <sub>SS</sub> = 1.2V		2.0	4.5	7.0	μA	
Logic High Threshold	EN Pin		1.4	_	_	V	
Logic Low Threshold	EN Pin		_	_	0.4	V	
EN Pull Down Resistor	_		_	1	_	mΩ	
Thermal Shutdown Temperature	_		_	+160	_	°C	
Thermal Shutdown Hysteresis			_	+40	_	°C	

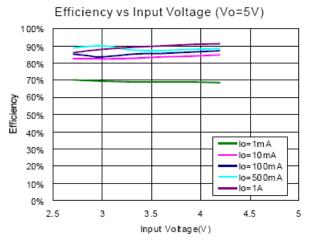


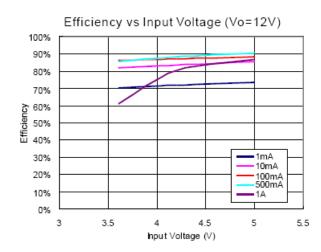
# Typical Operating Characteristics (@ T<sub>A</sub> = +25°C, V<sub>IN</sub> = V<sub>EN</sub> = 5V, V<sub>FREQ</sub> = 0, unless otherwise specified.)

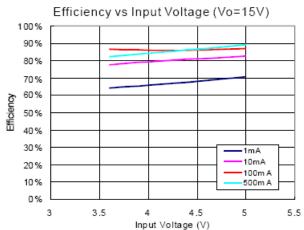






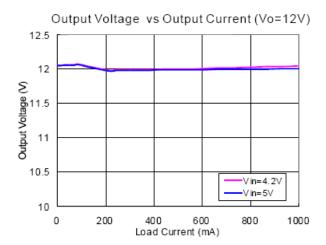


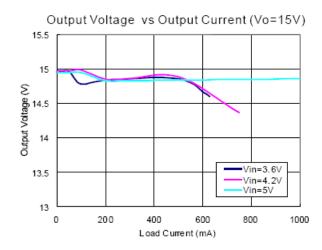


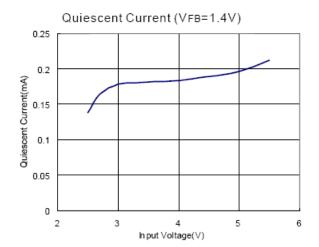


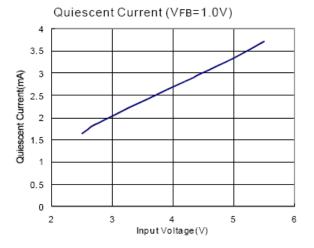


# Typical Performance Characteristics (@ T<sub>A</sub> = +25°C, V<sub>IN</sub> = V<sub>EN</sub> = 5V, V<sub>FREQ</sub> = 0, unless otherwise specified.) (continued)











### **Application Information**

The PAM242x are highly efficient step-up DC/DC converters that employ a current mode, fixed frequency pulse-width modulation (PWM) architecture with excellent line and load regulation. The PAM242x operate at constant switching frequency under medium to high load current conditions. At light loads, these devices operate in a pulse-skipping mode in order to improve light-load efficiency.

#### Soft-Start

The PAM242x offer a programmable soft-start function, which minimizes inrush current during startup. The soft-start period is programmed by connecting a 10nF capacitor between SS and Ground. Operation of the soft-start function is as follows: when the IC is disabled, SS is actively discharged to Ground. Upon enabling the IC, CSS is charged with a 4.5µA current so that the voltage at SS increases in a controlled manner. The peak inductor current is limited by the voltage at SS, so that the input current is limited until the soft-start period expires, and the regulator can achieve its full output current rating.

#### **Setting the Output Voltage**

The PAM242x feature external adjustable output voltages of up to 24V. To program the output voltage, simply connect a resistive voltage divider between the output, FB, and GND, with resistors set according to the following equation:

$$R1 = R2x \left[ \left( \frac{V_{OUT}}{V_{FB}} \right) - 1 \right]$$

Where V<sub>FB</sub> is 1.262V.

#### **Rectifier Selection**

For optimal performance, the rectifier should be a Schottky rectifier that is rated to handle both the output voltage as well as the peak switch current.

#### **Open Voltage Protection**

The PAM242x features internal automatic overvoltage protection, when feedback voltage is higher than 115%.

#### **Open Protection**

Once the outputs achieve regulation, the controller will automatically disable if the voltage at FB falls below 0.2V. This prevents the controller from running open-loop and potentially damaging the IC and load.

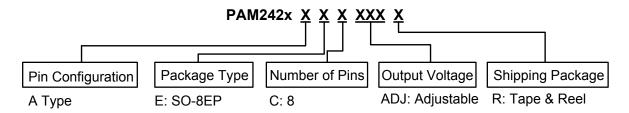
#### Shutdown

Drive EN low to disable the IC and reduce the supply current to just  $0.1\mu A$ . As with all nonsynchronous step-up DC/DC converters, the external Schottky diode provides a DC path from the input to the output in shutdown. As a result, the output drops to one diode voltage drop below the input in shutdown.

The PAM242x both feature integrated thermal overload protection. Both devices are automatically disabled when their junction temperatures exceed +160°C, and automatically re-enable when the die temperature decreases by +40°C.



## **Ordering Information**

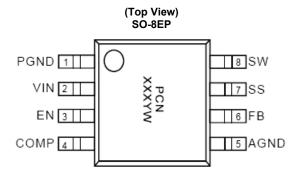


Part Number	Peak Current	Package Type	Standard Package	Status (Note 4)
PAM2421AECADJR	3A	SO-8EP	2500 Units/Tape & Reel	NRND
PAM2422AECADJR	4.5A	SO-8EP	2500 Units/Tape & Reel	EOL
PAM2423AECADJR	5.5A	SO-8EP	2500 Units/Tape & Reel	Active

Notes:

- 4. PAM2423AECADJR is Active. All other versions are NRND or EOL. For recommended alternatives to NRND/EOL devices, contact us at https://www.diodes.com/about/contact-us/.
- 5. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/

## **Marking Information**



PCN : Product Code of PAM242x

XXX: Internal Code

Y: Year 0~9

W : Week: A~Z: 1~26 weeks; a~z: 27~52 weeks;

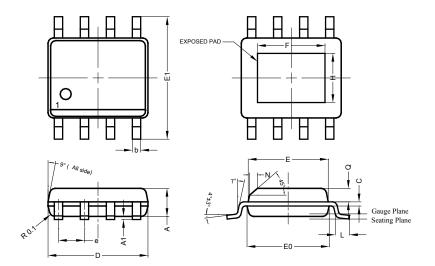
z represents 52 and 53 weeks



## **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### SO-8EP

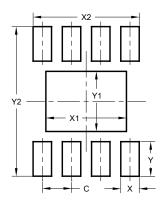


SO-8EP				
Dim	Min	Max	Тур	
Α	1.40	1.50	1.45	
A1	0.00	0.13	-	
b	0.30	0.50	0.40	
C	0.15	0.25	0.20	
D	4.85	4.95	4.90	
Е	3.80	3.90	3.85	
E0	3.85	3.95	3.90	
E1	5.90	6.10	6.00	
e	ı	ı	1.27	
F	2.75	3.35	3.05	
Н	2.11	2.71	2.41	
L	0.62	0.82	0.72	
N	-	-	0.35	
ø	0.60	0.70	0.65	
All Dimensions in mm				

### **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### SO-8EP



Dimensions	Value (in mm)	
С	1.270	
Х	0.802	
X1	3.502	
X2	4.612	
Υ	1.505	
Y1	2.613	
Y2	6.500	

### **Mechanical Data**

- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.081 grams (Approximate)



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